

Linear Systems Ultra Low Leakage Low Drift Monolithic Dual JFET

The LS830 is a high-performance monolithic dual JFET featuring extremely low noise, tight offset voltage and low drift over temperature specifications, and is targeted for use in a wide range of precision instrumentation applications. The LS830 features a 5-mV offset and 10- $\mu\text{V}/^\circ\text{C}$ drift.

The hermetically sealed TO-71 & TO-78 packages are well suited for military applications.

(See Packaging Information).

LS830 Applications:

- Wideband Differential Amps
- High-Speed, Temp-Compensated Single-Ended Input Amps
- High-Speed Comparators
- Impedance Converters and vibrations detectors.

FEATURES		
ULTRA LOW DRIFT	$ V_{GS1-2}/T \leq 5\mu\text{V}/^\circ\text{C}$ TYP.	
ULTRA LOW LEAKGE	$I_G = 80\text{fA}$ TYP.	
LOW NOISE	$e_n = 70\text{nV}/\sqrt{\text{Hz}}$ TYP.	
LOW CAPACITANCE	$C_{ISS} = 3\text{pF}$ MAX.	
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)		
Maximum Temperatures		
Storage Temperature	-65°C to +150°C	
Operating Junction Temperature	+150°C	
Maximum Voltage and Current for Each Transistor – Note 1		
-V _{GSS}	Gate Voltage to Drain or Source	40V
-V _{DSO}	Drain to Source Voltage	40V
-I _{G(f)}	Gate Forward Current	10mA
-I _G	Gate Reverse Current	10 μA
Maximum Power Dissipation		
Device Dissipation @ Free Air – Total		40mW @ +125°C

MATCHING CHARACTERISTICS @ 25°C UNLESS OTHERWISE NOTED				
SYMBOL	CHARACTERISTICS	VALUE	UNITS	CONDITIONS
$ V_{GS1-2}/T $ max.	DRIFT VS. TEMPERATURE	5	$\mu\text{V}/^\circ\text{C}$	$V_{DG}=10\text{V}$, $I_D=30\mu\text{A}$ $T_A=-55^\circ\text{C}$ to $+125^\circ\text{C}$
$ V_{GS1-2} $ max.	OFFSET VOLTAGE	25	mV	$V_{DG}=10\text{V}$, $I_D=30\mu\text{A}$

ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
BV _{GSS}	Breakdown Voltage	40	60	--	V	$V_{DS} = 0$ $I_D = 1\text{nA}$
BV _{GGO}	Gate-To-Gate Breakdown	40	--	--	V	$I_G = 1\text{nA}$ $I_D = 0$ $I_S = 0$
TRANSCONDUCTANCE						
Y _{FSS}	Full Conduction	70	300	500	μmho	$V_{DG} = 10\text{V}$ $V_{GS} = 0\text{V}$ $f = 1\text{kHz}$
Y _{FS}	Typical Operation	50	100	200	μmho	$V_{DG} = 10\text{V}$ $I_D = 30\mu\text{A}$ $f = 1\text{kHz}$
$ Y_{FS1-2}/Y_{FS} $	Mismatch	--	0.6	3	%	
DRAIN CURRENT						
I _{DSS}	Full Conduction	0.5	--	10	mA	$V_{DG} = 10\text{V}$ $V_{GS} = 0\text{V}$
$ I_{DSS1-2}/I_{DSS} $	Mismatch at Full Conduction	--	1	5	%	
GATE VOLTAGE						
V _{GS(off)} or V _p	Pinchoff voltage	0.6	2	4.5	V	$V_{DS} = 10\text{V}$ $I_D = 1\text{nA}$
V _{GS(on)}	Operating Range	--	--	4	V	$V_{DS} = 10\text{V}$ $I_D = 30\mu\text{A}$
GATE CURRENT						
-I _{Gmax.}	Operating	--	--	0.1	pA	$V_{DG} = 10\text{V}$ $I_D = 30\mu\text{A}$
-I _{Gmax.}	High Temperature	--	--	0.1	nA	$T_A = +125^\circ\text{C}$
-I _{GSSmax.}	At Full Conduction	--	--	0.2	pA	$V_{DS} = 0$
-I _{GSSmax.}	High Temperature	5	5	0.5	nA	$V_{GS} = 0\text{V}$, $V_{GS} = -20\text{V}$, $T_A = +125^\circ\text{C}$
I _{GGO}	Gate-to-Gate Leakage	--	1	--	pA	$V_{GG} = 20\text{V}$
OUTPUT CONDUCTANCE						
Y _{OSS}	Full Conduction	--	--	5	μmho	$V_{DG} = 10\text{V}$ $V_{GS} = 0\text{V}$
Y _{OS}	Operating	--	--	0.5	μmho	$V_{DG} = 10\text{V}$ $I_D = 30\mu\text{A}$
COMMON MODE REJECTION						
CMR	$-20 \log V_{GS1-2}/V_{DS} $	--	90	--	dB	$\Delta V_{DS} = 10$ to 20V $I_D = 30\mu\text{A}$
	$-20 \log V_{GS1-2}/V_{DS} $	--	90	--	dB	$\Delta V_{DS} = 5$ to 10V $I_D = 30\mu\text{A}$
NOISE						
NF	Figure	--	--	1	dB	$V_{DS} = 10\text{V}$ $V_{GS} = 0\text{V}$ $R_G = 10\text{M}\Omega$ $f = 100\text{Hz}$ $\text{NBW} = 6\text{Hz}$
e _n	Voltage	--	20	70	nV/ $\sqrt{\text{Hz}}$	$V_{DS} = 10\text{V}$ $I_D = 30\mu\text{A}$ $f = 10\text{Hz}$ $\text{NBW} = 1\text{Hz}$
CAPACITANCE						
C _{ISS}	Input	--	--	3	pF	$V_{DS} = 10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$
C _{RSS}	Reverse Transfer	--	--	1.5	pF	$V_{DS} = 10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$
C _{DD}	Drain-to-Drain	--	--	0.1	pF	$V_{DS} = 10\text{V}$, $I_D = 30\mu\text{A}$

Note 1 – These ratings are limiting values above which the serviceability of any semiconductor may be impaired

Available Packages:

LS830 / LS830 in TO-71 & TO-78
LS830 / LS830 available as bare die
Please contact [Micross](http://www.micross.com) for full package and die dimensions

TO-71 & TO-78 (Top View)

